

Then,
$$|0\mu| : \frac{1}{2} (230\mu) \binom{\omega}{L}_{M_1} | [0.9 - 0.93 - 0.37]^2$$

$$|10| : \frac{1}{2} (230) \binom{\omega}{L}_{M_1} | [0.7]^2.$$

$$|\frac{\omega}{L}_{M_1}| : \frac{10}{(15.07)^2} : 2.1739$$

$$|\frac{\omega}{L}_{M_1}| : \frac{\omega}{L}_{M_1} = 2.1339$$

$$|70| : \frac{1}{AID} = \frac{1}{0.1(10\mu)} = 1000KD$$

$$|(70)_{M_1}| : (70)_{M_2} : :$$

$$9m = \frac{2ID}{Vsg-Vtp} = \frac{2(10\mu)}{0.39} = 51.3 \mu S$$
 $(70)M3 = (70)M4 = \frac{1}{\lambda ID} = 1000 KD$

For M5 (consider some in stage 2)

M5 on
$$(Vsg)_s > (Vtn)_p$$
 ($Vsd)_u > (Vsg)_u - (Vtn)_p$ [$Vsl)_d = (Vg)_s$]

 $1.8 - (Vg)_s > 0.39$ $- (Vg)_s > -(Vg)_d - Vtp$
 $(Vg)_s \geq 1.41$ ($Vg)_s \geq 1.64V$

and $(Vg)_s > 0.53$
 $(Vg)_s = 1.02V$
 $(Vg)_s = 1.02V$

$$80\mu = \frac{1}{2} (100\mu) (\frac{W}{W})^{2} (1.8 - 1.02 - 0.39)^{2}$$

$$(\frac{W}{L})^{2} = \frac{2(80\mu)}{2(80\mu)} (\frac{1}{2} - 1.02 - 0.39)^{2}$$

$$(\frac{W}{L})^{2} = \frac{2(80\mu)}{2(80\mu)} (\frac{1}{2} - 1.02 - 0.39)^{2}$$

$$\frac{(I)_{6}}{(W|L)_{6}} = \frac{(I)_{N}db}{(W|L)_{N}dt}$$

$$\frac{80}{(W|L)_{6}} = \frac{2}{2}$$

$$\frac{2}{(W|L)_{6}}$$

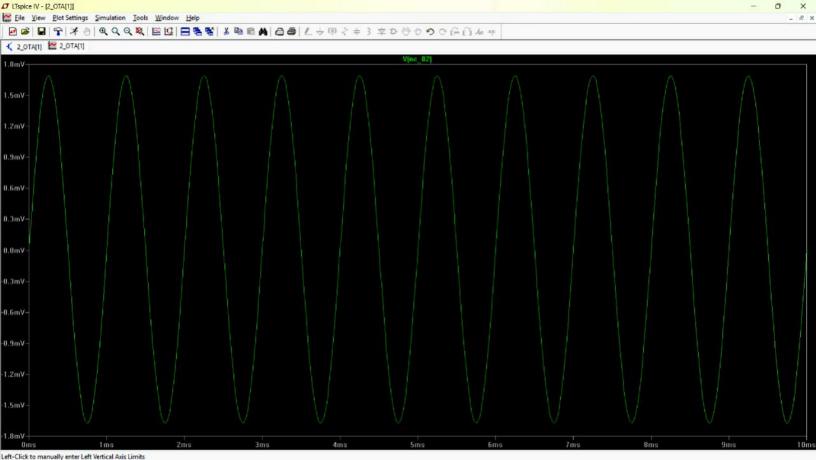
Transistor	WIL	9m	b vudrive	70	to
MNOS { M2	2.1739	100 pts	0'2V	1000 K D	RopiA
	2.1739	100 ps	0.51	1000K A	
PM OS { Ma	1:314	51.3715	0.34V	1000k2	
	1.314	51.3µs	0.34V	1000KA	soh
PMDS MS	10.212	410.2545	0.34V	125KR	804
NMOS M6	80	1777 MS	0.09V	185K52	804
ur Mo	20	444.44S	0.04V	500Kn	40
yernu Mz	20 2	, yaraa ha	0 09 V	5000K 12	21

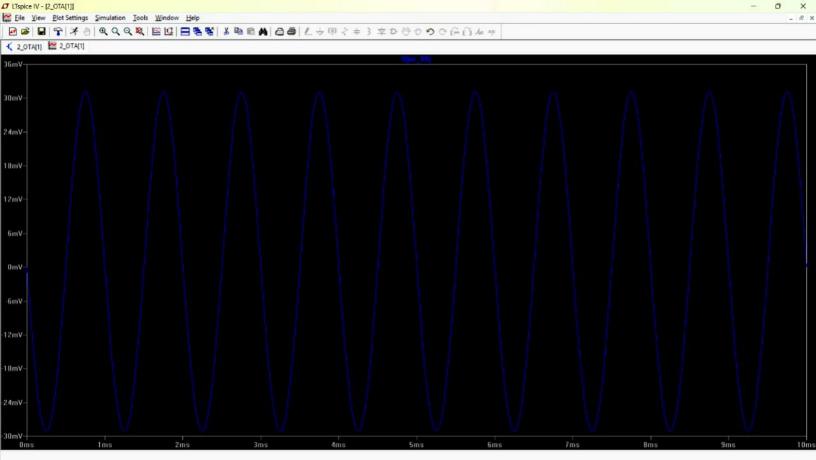
Gain of 1st stage $(AV)_{i}^{2} = \frac{1.7mV - (-1.7mV)}{20\mu} = \frac{3.4mV}{20\mu} = 170 = 44.6dB$ and stage $(AV)_{2}^{2} = \frac{30mV - (-30mV)}{20\mu} = \frac{60mV}{20\mu} = 3000 = 69.54dB$

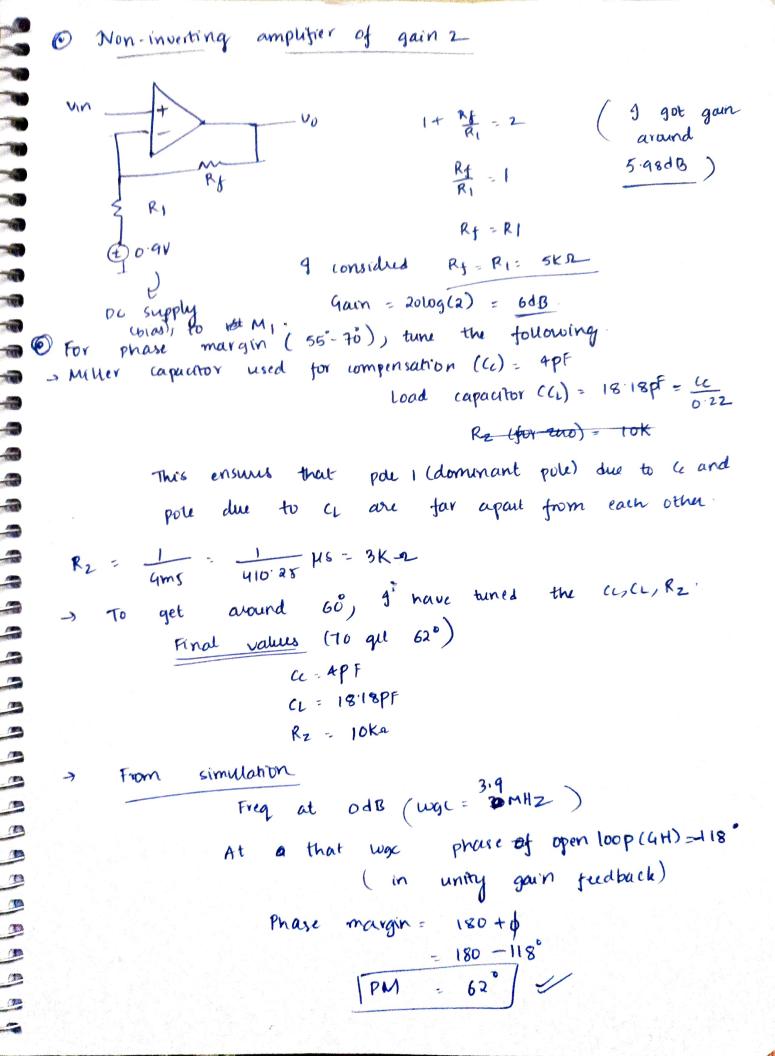
Overall gain -> 114.14dB

Power consumed > 2012 + 80 = 102 MA V= 1.8 V

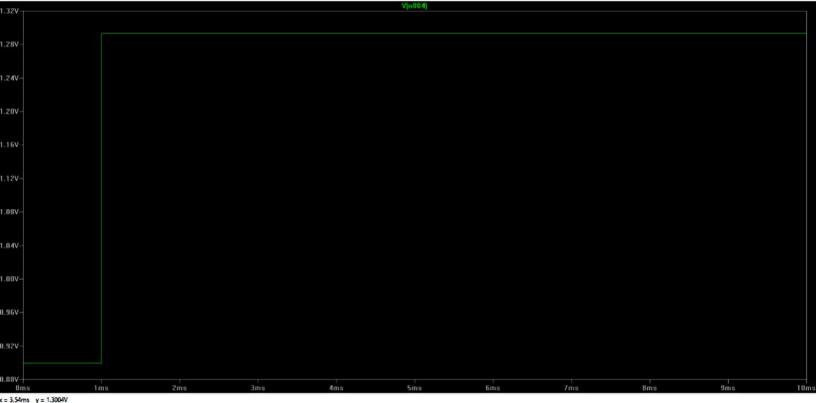
Power = 183 MW

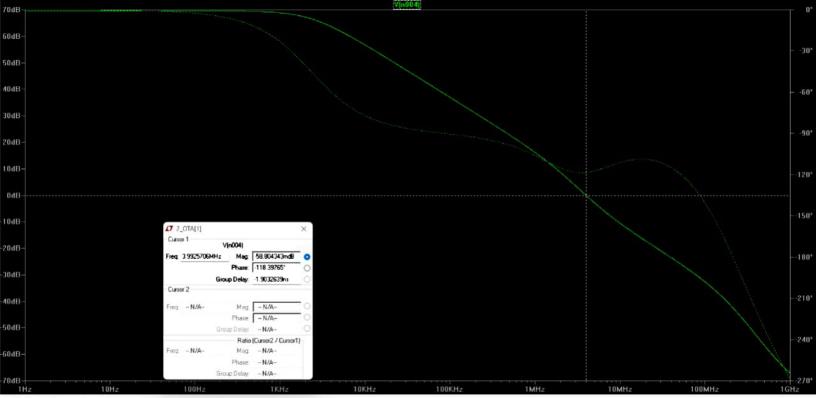












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